PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Attn: OIPE

Masahiro SAKURADA et al.

Application No.:

10/538,878

Docket No.: 124231

Filed: June 14, 2005

For:

METHOD OF PRODUCING P-DOPED SILICON SINGLE CRYSTAL AND P-

DOPED N-TYPE SILICON SINGLE CRYSTAL WAFER

REQUEST FOR CORRECTION OF PALM RECORDS

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Attached is a photocopy of the original filing receipt on which errors have been corrected in red. These errors are being brought to the attention of the Patent and Trademark Office so that it may correct its records. The originally filed application data sheet is attached.

Respectfully submitted,

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WPB:JOC/mps

Date: December 29, 2005

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CONFIRMATION NO. 8834

25944 OLIFF & BERRIDGE, PLC P.O. BOX 19928 ALEXANDRIA, VA 22320

DEC 1 5 2005

FILING RECEIPT *OC00000017601533

Date Mailed: 12/12/2005

Receipt is acknowledged of this regular Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please mail to the Commissioner for Patents P.O. Box 1450 Alexandria Va 22313-1450. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

Applicant(s)

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Power of Attorney: The patent practitioners associated with Customer Number 25944.

Domestic Priority data as claimed by applicant

This application is a 371 of PCT/JP03/16794 12/25/2003

Foreign Applications

JAPAN 2003-10436 01/17/2003

Projected Publication Date: 03/16/2006

Non-Publication Request: No

Early Publication Request: No

Title

METHOD OF

Process for producing p-doped silicon single crystal and p-doped n-type silicon single crystal wafer

Preliminary Class

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